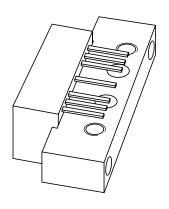
DISCRETE SEMICONDUCTORS

DATA SHEET



BGY587B 550 MHz, 27 dB gain push-pull amplifier

Product specification Supersedes data of 1997 Apr 10 2001 Oct 22





550 MHz, 27 dB gain push-pull amplifier

BGY587B

FEATURES

- · Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

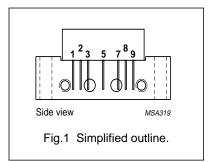
DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of +24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION	
1	input	
2	common	
3	common	
5	+V _B	
7	common	
8	common	
9	output	

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	26.2	27.8	dB
		f = 550 MHz	27.5	_	dB
I _{tot}	total current consumption (DC)	V _B = +24 V	_	340	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER		MAX.	UNIT
Vi	RF input voltage	_	55	dBmV
T _{stg}	storage temperature		+100	°C
T _{mb}	operating mounting base temperature		+100	°C
V _B	DC supply voltage		+28	V

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CHARACTERISTICS

Table 1 Bandwidth 40 to 550 MHz; $T_{case} = 30 \, ^{\circ}\text{C}$; $Z_S = Z_L = 75 \, \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	26.2	27.8	dB
		f = 550 MHz	27.5		dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.5	2.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz	_	±0.4	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 550 MHz	18	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 550 MHz	18	-	dB
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	_	-57	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-60	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz	_	-57	dB
d_2	second order distortion	note 1	_	-68	dB
Vo	output voltage	d _{im} = -60 dB; note 2	61	_	dBmV
F	noise figure	f = 550 MHz	_	6.5	dB
I _{tot}	total current consumption	DC value; $V_B = +24 \text{ V}$; note 3	_	340	mA

Notes

```
 \begin{array}{ll} \text{1.} & f_p = 55.25 \text{ MHz}; \ V_p = 44 \text{ dBmV}; \\ f_q = 493.25 \text{ MHz}; \ V_q = 44 \text{ dBmV}; \\ & \text{measured at } f_p + f_q = 548.5 \text{ MHz}. \end{array}
```

2. Measured according to DIN45004B;

 $f_p = 540.25 \text{ MHz}; V_p = V_o = 66.5 \text{ dBmV};$

 $f_q = 547.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$

 $f_r = 549.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 538.25$ MHz.

3. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

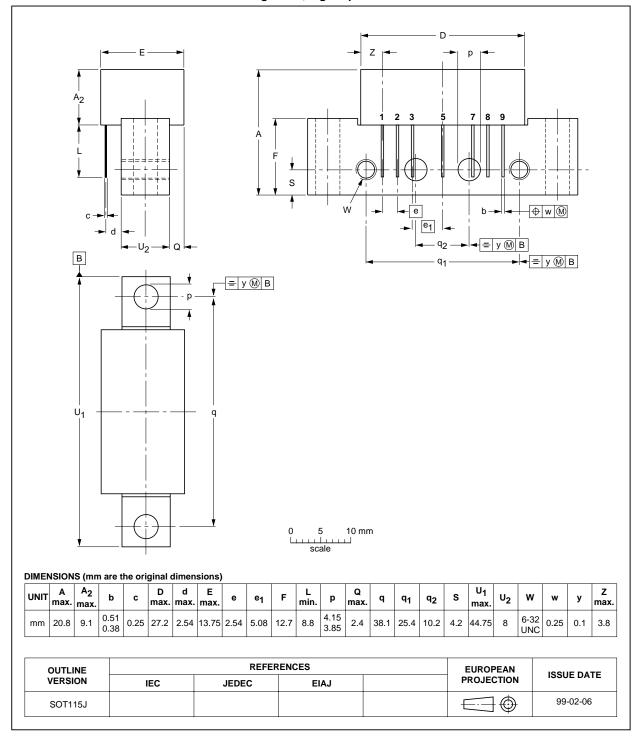
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PACKAGE OUTLINE

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

SOT115J



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DATA SHEET STATUS

DATA SHEET STATUS(1)	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

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550 MHz, 27 dB gain push-pull amplifier

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NOTES

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NOTES

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Contact information

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

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